

## Digital Attenuator, 1 Bit, 10 dB Step DC - 2.0 GHz

AT-266  
V4

### Features

- Single 10 dB Step
- Low Loss: 0.3 dB @ 900 MHz
- Low Cost SOT-25 Package

### Description

M/A-COM's AT-266 is a 1 bit, 10 dB step GaAs MMIC digital attenuator in a low cost SOT-25 surface mount plastic package. The AT-266 is ideally suited for use where high accuracy, very low power consumption and low intermodulation products are required. Typical applications include radio, wireless LANs, GPS equipment and other gain/level control circuits.

The AT-266 is fabricated using a mature GaAs MMIC process featuring full chip passivation for increased performance and reliability.

### Ordering Information

Part Number	Package
AT-266	Bulk Packaging
AT-266TR	1000 piece reel

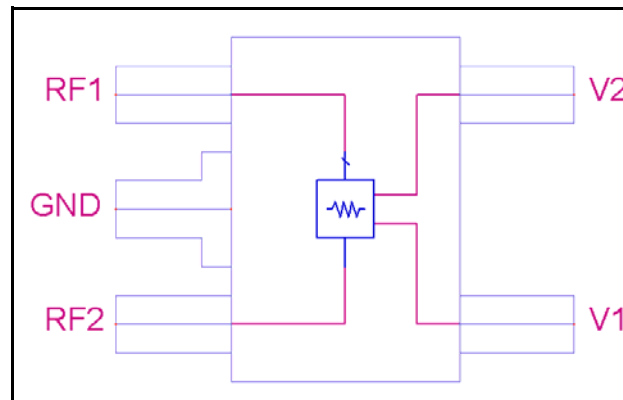
Note: Reference Application Note M513 for reel size information.

### Absolute Maximum Ratings <sup>1,2</sup>

Parameter	Absolute Maximum
Input Power 50 MHz 500 - 2000 MHz	+27 dBm +34 dBm
Control Voltage	$-8.5 \text{ V} \leq V_c \leq +8 \text{ V}$
Operating Temperature	$-40^\circ\text{C}$ to $+85^\circ\text{C}$
Storing Temperature	$-65^\circ\text{C}$ to $+150^\circ\text{C}$

1. Exceeding any one or combination of these limits may cause permanent damage to this device.
2. M/A-COM does not recommend sustained operation near these survivability limits.

### Functional Block Diagram



### Pin Configuration

Pin No.	Function	Description
1	RF1	RF In/Out
2	GND	RF Ground
3	RF2	RF In/Out
4	V1	Control Voltage
5	V2	Control Voltage

### Truth Table <sup>3,4,5</sup>

V1	V2	Attenuation State
0	1	10 dB
1	0	Insertion Loss

3. For positive voltage control, external DC blocking capacitors are required on all RF ports (pins 1, 2 and 3).
4. Differential voltage,  $V(\text{state } 1) - V(\text{state } 0)$ , must be  $+2.8 \text{ V}$  minimum and less than  $8 \text{ V}$ .
5.  $0 = -8 \text{ V}$  to  $0.2 \text{ V}$ ,  $1 = -0.2 \text{ V}$  to  $8 \text{ V}$

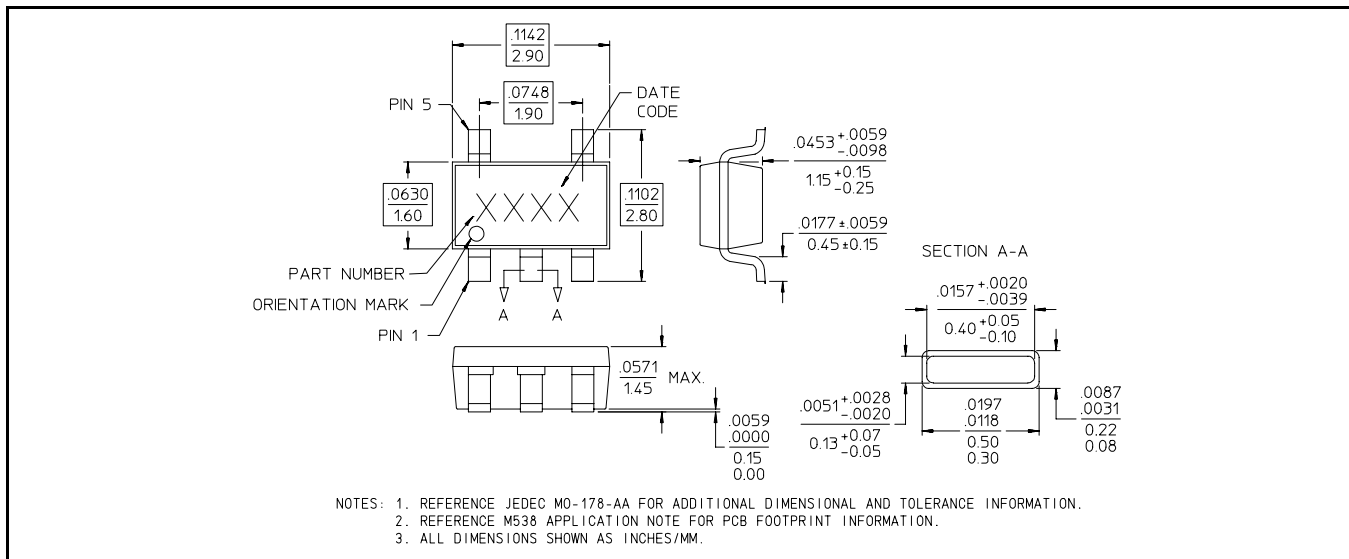
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**Electrical Specifications:  $T_A = 25^\circ\text{C}$ ,  $V_C = 0\text{ V} / -3\text{ V}$ ,  $Z_0 = 50\ \Omega$**

Parameter	Test Conditions	Units	Min.	Typ.	Max.
Insertion Loss	0 - 1 GHz	dB	—	0.3	0.45
	1 - 2 GHz	dB	—	0.5	0.7
Attenuation	DC - 1 GHz	dB	9.6	10	10.4
	1 - 2 GHz	dB	9.5	10	10.5
VSWR	0 - 2 GHz	Ratio	—	1.4:1	1.5:1
$IP_3$	2 Tone @ 0 dBm, 5 MHz spacing	dBm	42	50	—
P1dB	1 GHz	dBm	23	28	—
Trise, Tfall	10% to 90% RF, 90% to 10% RF	nS	—	5	20
Ton, Toff	50% Control to 90% RF, 50% Control to 10% RF	nS	—	10	25
Transients	In Band	mV	—	6	10
Control Current	$ V_C  = 3\text{ V}$	$\mu\text{A}$	—	25	—

**SOT-25 Plastic Package**



**Handling Procedures**

Please observe the following precautions to avoid damage:

**Static Sensitivity**

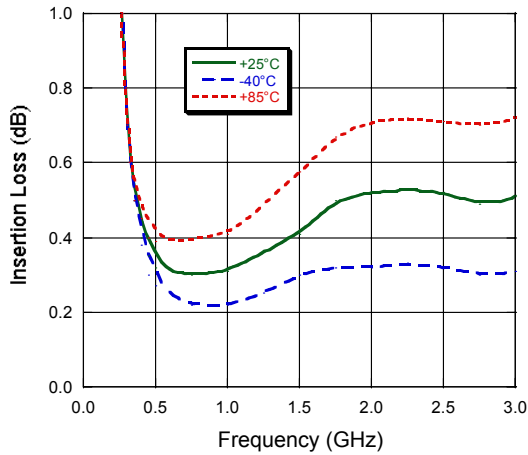
Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

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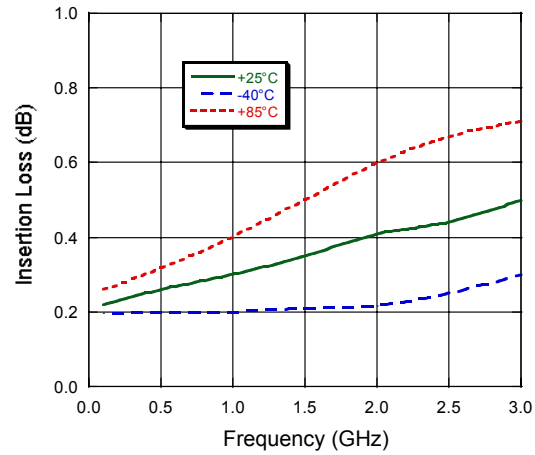
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**Typical Performance Curves (39 pF capacitors used for positive voltage control)**

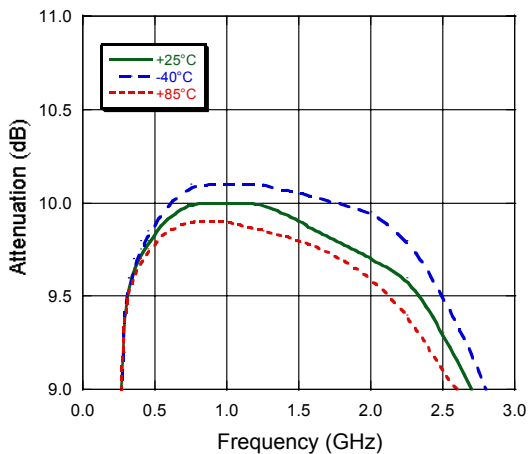
*Insertion Loss (Positive Control)*



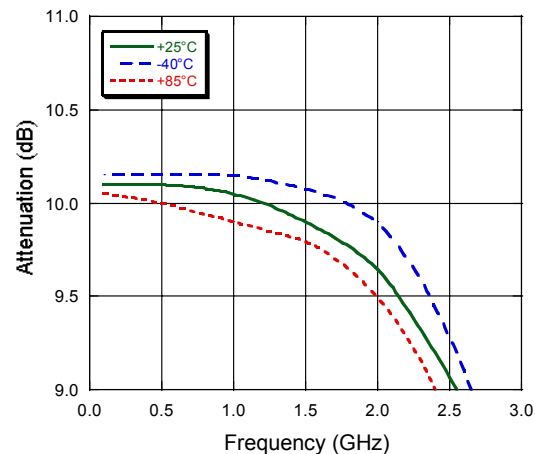
*Insertion Loss (Negative Control)*



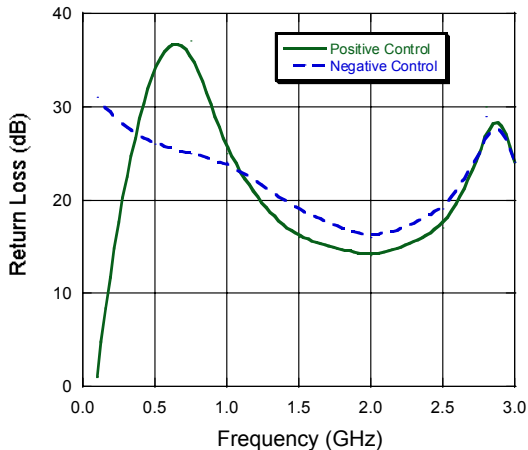
*Relative Attenuation (Positive Control)*



*Relative Attenuation (Negative Control)*



*Return Loss (Reference State)*



*Return Loss (10 dB State)*

